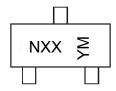


## **Marking Information**



NXX = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2016		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	D			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

### Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		V <sub>CC</sub>	50	V
Input Voltage, (1) to (2)	DDTD113EU DDTD123EU DDTD143EU DDTD114EU DDTD122JU DDTD113ZU DDTD123YU DDTD133HU	Vin	-10 to +10 -10 to +12 -10 to +30 -10 to +40 -5 to +5 -5 to +10 -5 to +12 -6 to +20	V
Input Voltage, (2) to (1)	DDTD123TU DDTD143TU DDTD114TU DDTD114GU	V <sub>EBO</sub> (MAX)	5	٧
Output Current	All	Ic	500	mA

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

5. Mounted on FR4 PC Board with minimum recommended pad layout. Note:



Electrical Characteristics (@ TA = +25°C, unless otherwise	e specified.) R1, R2 Types
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Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Onaracienstic	DDTD113EU	Symbol		יאָרי	IVIAA	Jint	rest containon
Input Valtage	DDTD113EU DDTD123EU DDTD143EU DDTD114EU DDTD122JU DDTD113ZU DDTD123YU DDTD133HU	$V_{I(off)}$	0.5 0.5 0.5 0.5 0.5 0.3 0.3	_	_	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
Input Voltage	DDTD113EU DDTD123EU DDTD143EU DDTD114EU DDTD122JU DDTD113ZU DDTD123YU DDTD133HU	V <sub>I(on)</sub>			3.0 3.0 3.0 3.0 3.0 2.0 2.0	V	$V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 10mA$ $V_O = 0.3V$ , $I_O = 30mA$ $V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$
Output Voltage		$V_{O(on)}$			0.3V	V	$I_O/I_I = 50$ mA/2.5mA
Input Current	DDTD113EU DDTD123EU DDTD143EU DDTD114EU DDTD122JU DDTD113ZU DDTD123YU DDTD133HU	lı	_		7.2 3.8 1.8 0.88 28 7.2 3.6 2.4	mA	V <sub>1</sub> = 5V
Output Current		I <sub>O(off)</sub>	_	_	0.5	μА	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	DDTD113EU DDTD123EU DDTD143EU DDTD114EU DDTD122JU DDTD113ZU DDTD123YU DDTD133HU	Gı	33 39 47 56 47 56 56 56	_	_	_	V <sub>O</sub> = 5V, I <sub>O</sub> = 50mA
Gain-Bandwidth Product (Note 6)		f <sub>T</sub>		200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

# Electrical Characteristics (@ T<sub>A</sub> = 25°C unless otherwise specified) R1-Only, R2-Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	_	_	V	I <sub>C</sub> = 50μA	
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	40	_	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	DDTD123TU DDTD143TU DDTD114TU DDTD114GU	BV <sub>EBO</sub>	5	_	_	V	I <sub>E</sub> = 50μA I <sub>E</sub> = 50μA I <sub>E</sub> = 50μA I <sub>E</sub> = 720μA
Collector Cutoff Current		I <sub>CBO</sub>	_	_	0.5	μΑ	V <sub>CB</sub> = 50V
Emitter Cutoff Current	DDTD123TU DDTD143TU DDTD114TU DDTD114GU	I <sub>EBO</sub>	  300	_	0.5 0.5 0.5 580	μА	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	_	_	0.3	V	I <sub>C</sub> = 50mA, I <sub>B</sub> = 2.5mA
DC Current Transfer Ratio	DDTD123TU DDTD143TU DDTD114TU DDTD114GU	h <sub>FE</sub>	100 100 100 56	250 250 250 —	600 600 600	_	I <sub>C</sub> = 5mA, V <sub>CE</sub> = 5V
Gain-Bandwidth Product (Note 6)		f⊤		200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

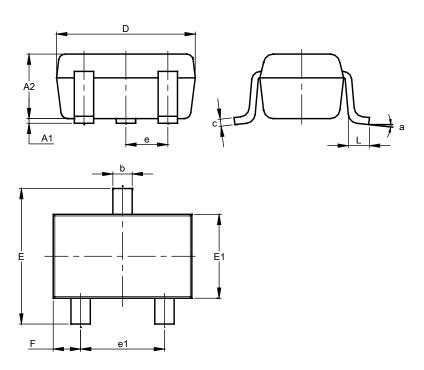
Note: 6. Transistor - for reference only



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**

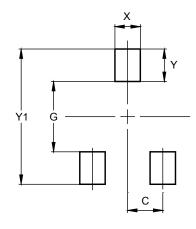


		Tana				
SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
C	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°	-			
All	Dimen	sions	in mm			

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**



Dimensions	Value		
Dillielisions	(in mm)		
С	0.650		
G	1.300		
Х	0.470		
Υ	0.600		
Y1	2.500		



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